Two Channel Kondo in a Modified SET

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http://www.weizmann.ac.il/condmat/oreg_group.html

Outline

- Fermi liquid vs. non Fermi Liquids (NFL).
- Fermi edge singularity (FES).
- Single channel Kondo effect Schrieffer-Wolff and Coulomb gas.
- Multi-channel Kondo effect an academic exercise (Nozieres, Blandin and Zawadowski).
- Realization of multi-channel Kondo effect (MCK) in a single electron transistor (SET).
- Possible measurements of MCK in a SET.
- Summary.

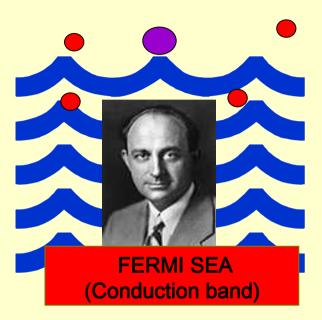
2-Channel Vs 1-Channel Kondo

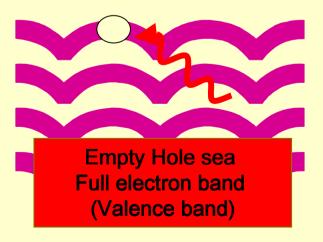
$T << T_K$	Single Channel	Two Channel
Entropy	$a \xrightarrow{T}_{T_K} \to 0 = Log[1]$	$\frac{1}{2} Log [2]$
Spin Susceptibility	$b \frac{(g\mu_B)^2}{T_K}$	$\beta \frac{(g\mu_B)^2}{T_K} Log(\frac{T_K}{T})$
Specific Heat	$a\frac{T}{T_K}$	$\alpha\left(\frac{T}{T_K}\right)Log\left(\frac{T_K}{T}\right)$
Conductance	$c_1 - c_2 \left(\frac{T}{T_K}\right)^2$	$\gamma_1 \pm \gamma_2 \sqrt{\frac{T}{T_K}}$

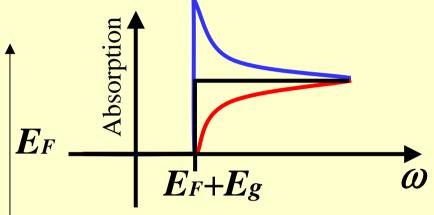
Fermi Liquid (FL) Non FL **Single Channel Kondo Two-Channel Kondo** dI/dVsd dI/dVsd $c_1 \left[1 - c_2 \left(\Theta / T_k \right)^2 \right]$ $\Theta \equiv \max[T, V_{sd}]$

Fermi Edge singularity

 E_g



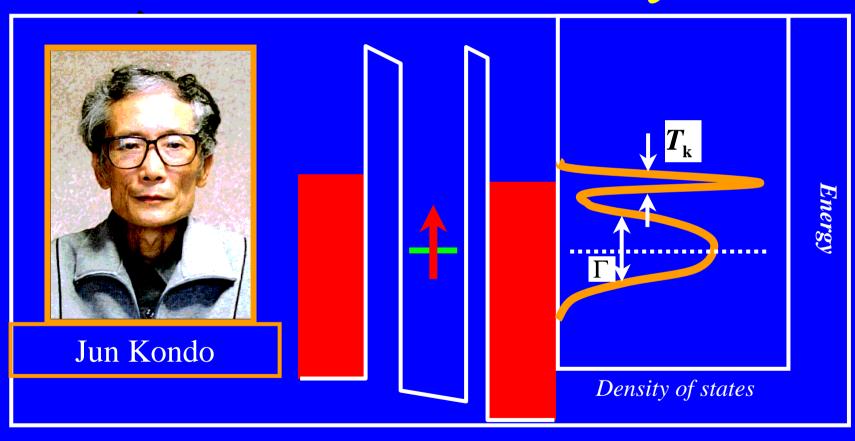




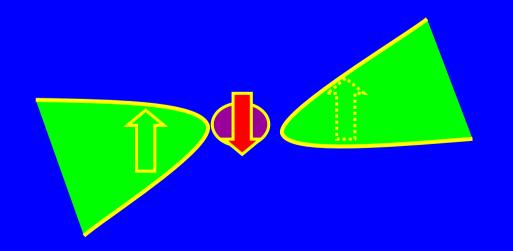
- •Attraction between valance hole and conduction electrons.
- Orthogonality "catastrophe"

Sudden potential + Many body effects

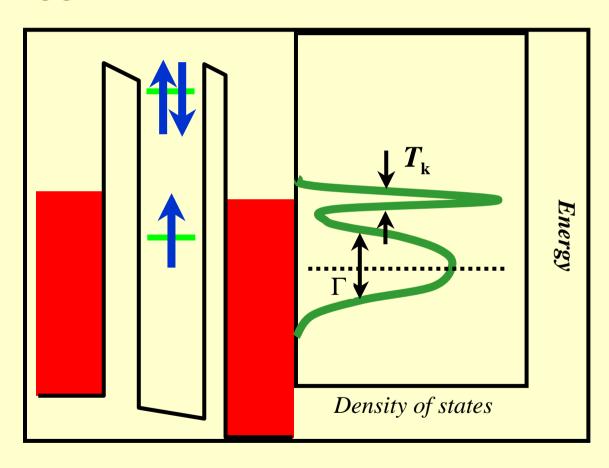
Single Channel Kondo and Anderson Model: Many FES



Spin -Charge Separation



Anderson → Haldane → Schrieffer-Wolff → Kondo → Resonance



Anderson Model

$$H = \sum_{ks} \varepsilon_{ks} l_{ks}^{\dagger} l_{ks} + \sum_{s} \varepsilon_{d}^{0} d_{s}^{\dagger} d_{s} + U n_{d\uparrow} n_{d\downarrow}$$

$$+ \sum_{ks} \left(V_{lk}^{*} l_{ks}^{\dagger} d_{s} + V_{lk} d_{s}^{\dagger} l_{ks} \right)$$

Schrieffer-Wolff

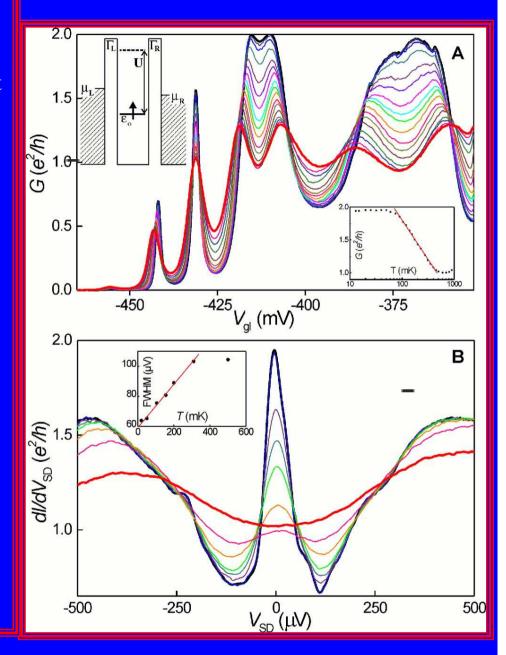
$$H = \sum_{ks} \varepsilon_{ks} l_{ks}^{+} l_{ks} + \sum_{kq} J^{kq} \left[S^{+} s^{-kq} + S^{-} s^{+kq} + 2S^{z} s^{zkq} \right]$$

$$S^{+} = d_{\uparrow}^{+} d_{\downarrow}, S^{-} = d_{\downarrow}^{+} d_{\uparrow}, S^{z} = \frac{1}{2} \left(d_{\uparrow}^{+} d_{\uparrow} - d_{\downarrow}^{+} d_{\downarrow} \right),$$

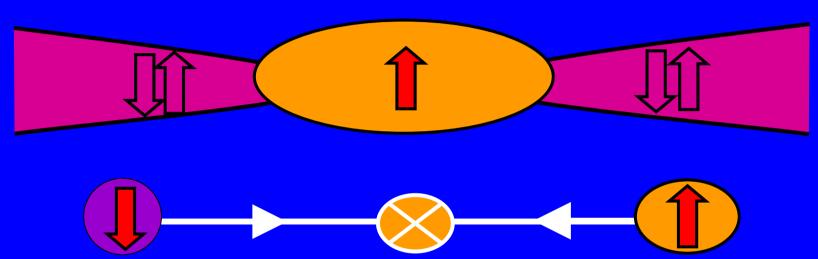
$$S^{+kq} = l_{k\uparrow}^{+} l_{q\downarrow}, S^{-kq} = l_{k\downarrow}^{+} l_{q\uparrow}, S^{zkq} = \frac{1}{2} \left(l_{k\uparrow}^{+} l_{q\uparrow} - l_{k\downarrow}^{+} l_{q\downarrow} \right)$$

$$J^{kq} = V_k V_q^* \left[\frac{1}{E_{\text{elec}} - E_{\text{init}}} + \frac{1}{E_{\text{hole}} - E_{\text{init}}} \right]$$

- (A) Coulomb oscillations in G versus $V_{\rm gl}$ at B=0.4 T for different temperatures. T ranges from 15 mK (thick black trace) up to 800 mK (thick red trace). $V_{\rm gr}$ is fixed at 448 mV. The red line in the right inset highlights the logarithmic T dependence between ~90 and ~500 mK for $V_{\rm gl}=-413$ mV. The left inset explains the variables used in the text with $T=T_{\rm L}+T_{\rm R}$. \mathcal{E}_0 is negative and measured from the Fermi level in the leads at equilibrium.
- (B) Differential conductance $dI/dV_{\rm SD}$ versus dc bias voltage between source and drain contacts $V_{\rm SD}$ for T ranging from 15 mK (thick black trace) up to 900 mK (thick red trace), at $V_{\rm gl} = 413~mV$ and B = 0.4 T. The inset shows that the width of the zero-bias peak, measured from the FWHM, increases linearly with T. The red line indicates a slope of $1.7~k_{\rm B}/e$. At 15 mK, the FWHM = $64~\mu$ V, and it starts to saturate around 300 mK.

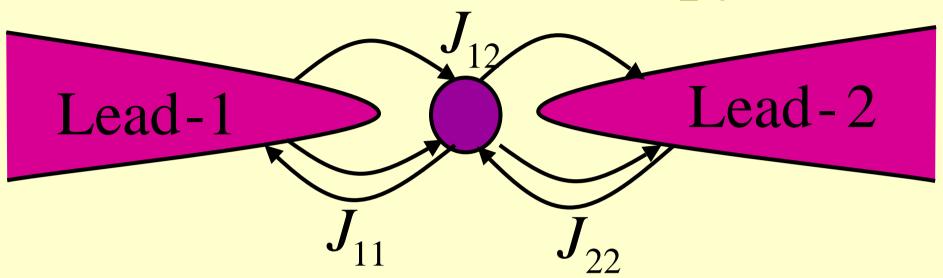


Multi - Channel Kondo



- RG, NRG
- Bethe Ansatz (Andrei, Wiegmann-Tsvelik)
- Conformal Field Theory (Affleck Ludwig)
- "Pseudo Particle" or "Slave Bosons"(Read Coleman, Ruckenstein Cox)
- Bosonization (Kivelson Emery)

Channel anisotropy



$$\begin{pmatrix}
J_{11} & J_{12} \\
J_{21} & J_{22}
\end{pmatrix} \Rightarrow \begin{pmatrix}
J_{1} & 0 \\
0 & J_{2}
\end{pmatrix} = \frac{1}{2} \begin{pmatrix}
J_{11} - J_{22} + \sqrt{(J_{11} - J_{22})^{2} + 4J_{12}J_{21}} & 0 \\
0 & J_{11} - J_{22} - \sqrt{(J_{11} - J_{22})^{2} + 4J_{12}J_{21}}
\end{pmatrix}$$

In Quantum dots

we can tune

$$J_1=J_2$$





$$m = 1,2$$
 and p

$$\widetilde{J} = J \bullet \mathrm{Dens}$$

$$\widetilde{J} = \widetilde{J}_m^2 - \widetilde{J}_m \sum_p \widetilde{J}_p^2.$$

Suggestions for 2CK Realizations:

~100 Publications/attempts to realize MCK

- Two level systems, "spins are isotropic channels"
 - Theo: Zawadowski, von Delft et al,
 - ■Exp: Dan Ralph and Burman.
- Coulomb blockade peak is a degenerate state
 - ■The. Matveev et al. (Requires a large dot, and smooth contacts)
 - Exp. Devoret et al. $\Delta \ll T_k \approx \sqrt{E_c \Gamma} e^{-E_c/\Gamma} \ll E_c$ Hard in real systems.
 - Schiller et al.

• Quadruple 2CK (Cox)

- Non equilibrium (Wen)
- Luttinger leads (Kim)

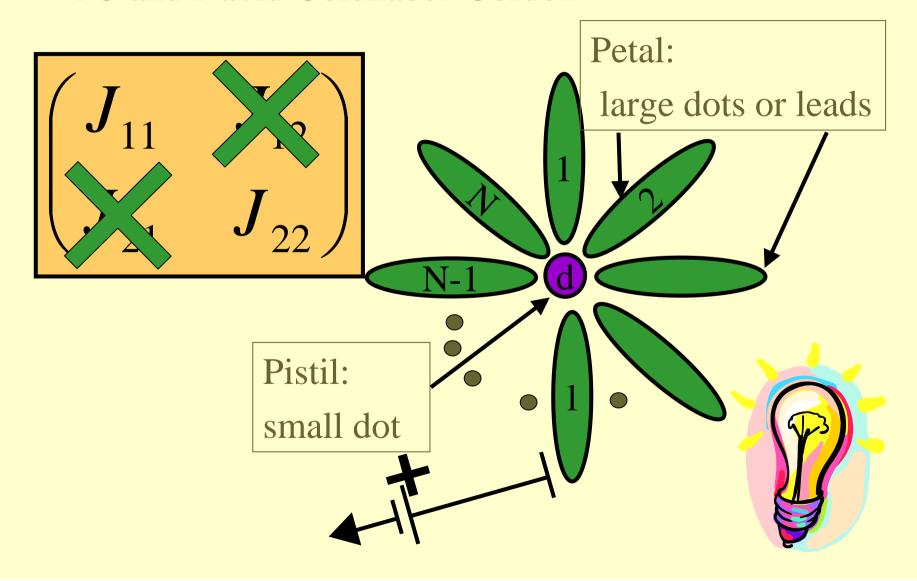
Charging energy
Lead-Dot Coupling const

Kondo temp.

Average level spacing

A simple realization of MCK

YO and David Goldhaber-Gordon

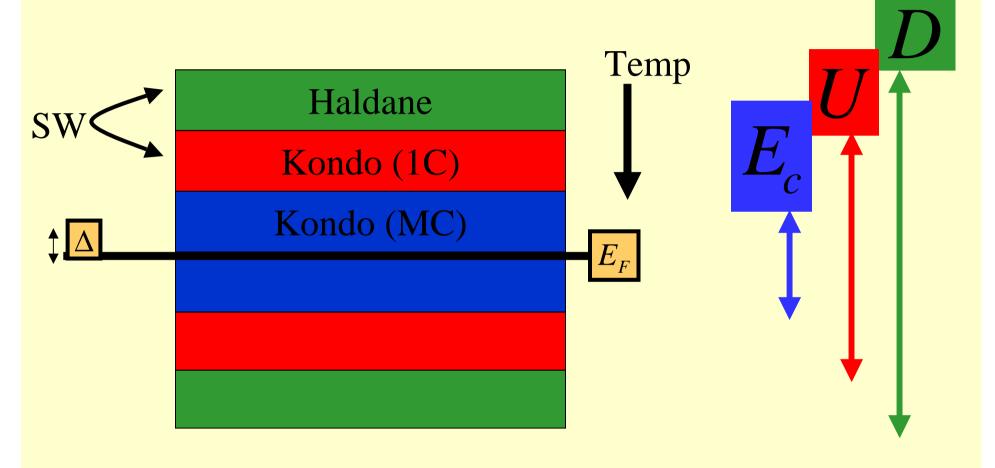


Generalized Anderson Model

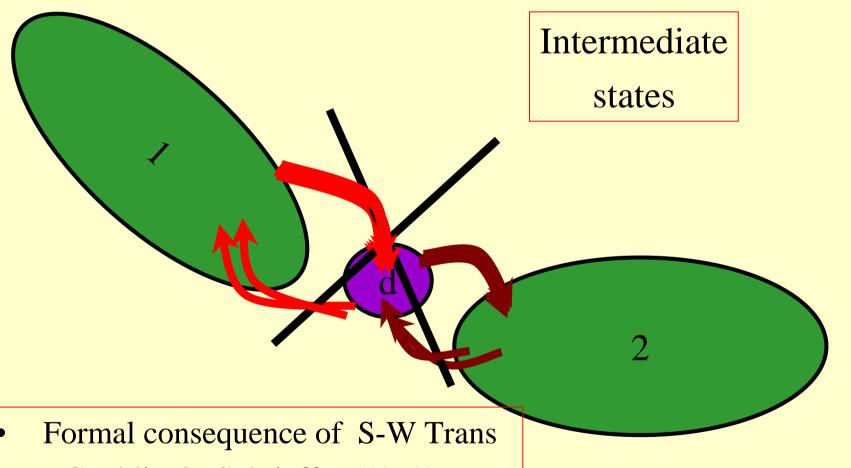
$$H = \sum_{kls} \mathcal{E}_{ks} l_{ks}^{+} l_{ks} + \sum_{s} \mathcal{E}_{d}^{0} d_{s}^{+} d_{s} + U n_{d} \uparrow n_{d} \downarrow$$

$$+ \sum_{l} \mathcal{E}_{cl} (n_{l} - N_{l})^{2}$$
Gate potential on large-dot-l
Number of electrons in large-dot-l
$$+ \sum_{ks} (V_{lk}^{*} l_{ks}^{+} d_{s} + V_{lk} d_{s}^{+} l_{ks})$$

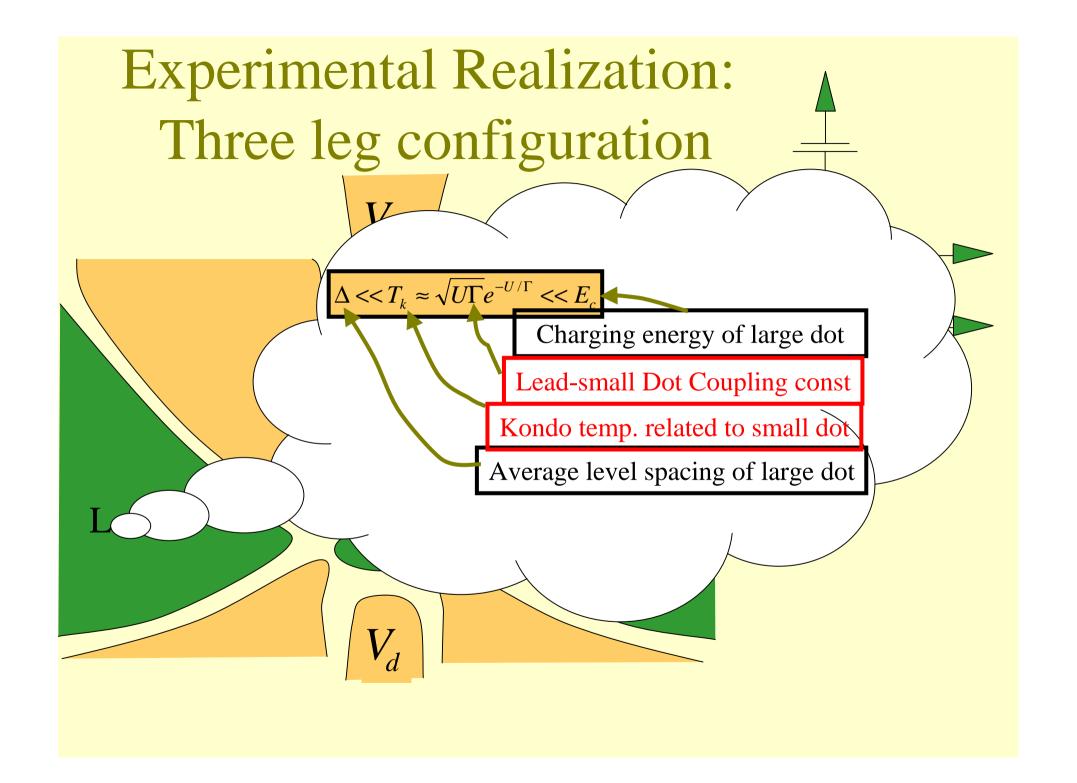
Analysis of the model



Neglect Higher Orders



- Coqblin & Schrieffer (1969)
- Smaller by a Factor U/T compare to two separate hops to the same dot

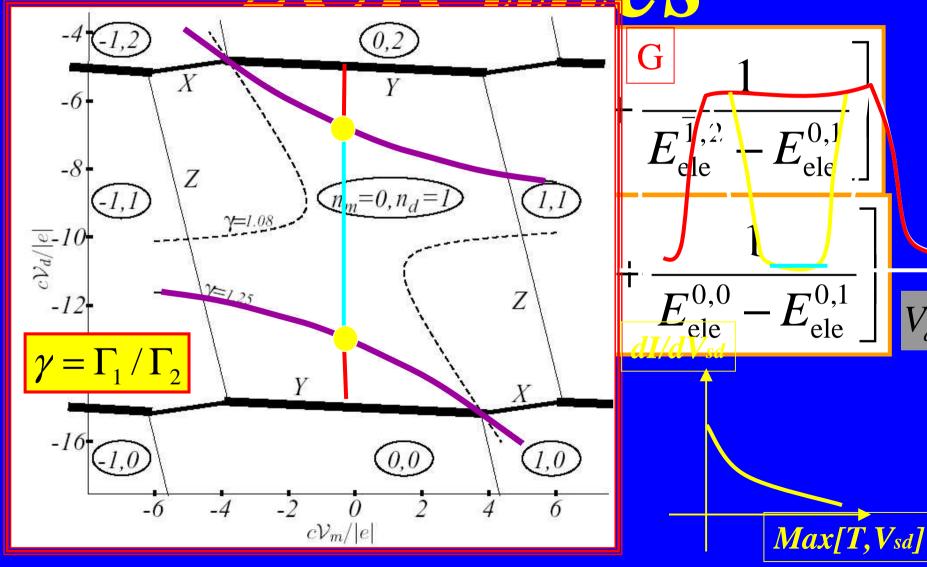


Hexagons

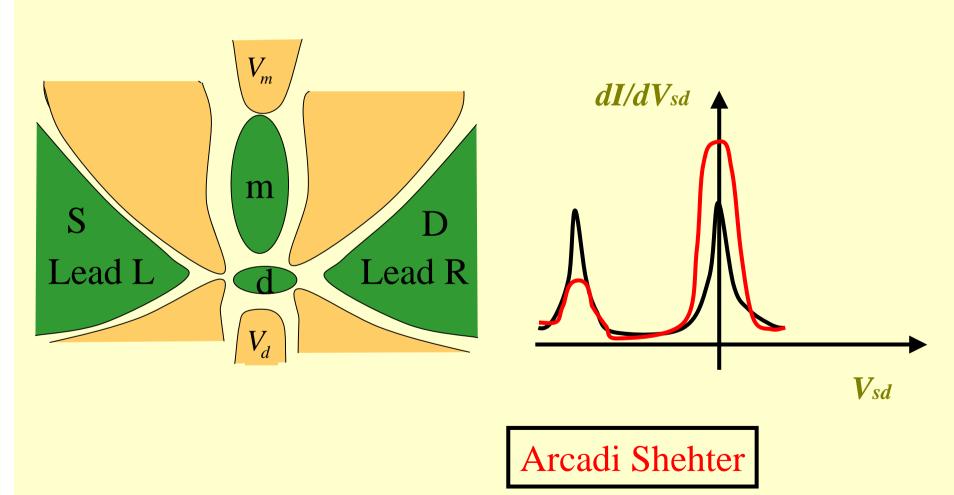
 $n_m = -1, n_d = 2$ $n_m = 0, n_d = 2$ $n_m = 1, n_d = 2$ $n_m = -1, n_d = 1$ $n_m = 0, n_d = 1$ $n_m = 1, n_d = 1$ $n_m = -1, n_d = 0$ $n_m = 0, n_d = 0$ $n_m = 1, n_d = 0$

 V_{m}

2CK lines



Suggestions for Experiments: Tunneling Density of states



Summary

- A Realization of *two (multi) channel Kondo* in a modified Single Electron Transistor.
 - More theory (Magnetic Field and Anisotropy, dependence on initial physical parameters, Dephasing, noise, pumping, tunneling DOS) and new experiments ...
- Model: small dot + interacting leads (channels):
 - > a Generalization in a new direction (each channel have different "electrochemical potential").
 - Generic model: many other types of petals will "do the job":
 - Luttinger liquid, Interacting disordered systems, Two 2D strongly interacting metals (Cuprates?), Environment with large impedance...